

BYT54A, BYT54B, BYT54D, BYT54G, BYT54J, BYT54K, BYT54M

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Vishay Semiconductors

Fast Avalanche Sinterglass Diode



FEATURES

- Glass passivated junction
- · Hermetically sealed package
- · Low reverse current
- · Soft recovery characteristics
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

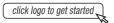


HALOGEN

FREE

949539

DESIGN SUPPORT TOOLS



MECHANICAL DATA

Case: SOD-57

Models Available

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 369 mg

APPLICATIONS

· Very fast rectification and switching diodes

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------------|----------------------------|--------|--|--|
| DEVICE NAME | MINIMUM ORDER QUANTITY | | | | |
| BYT54M | BYT54M-TR | 5000 per 10" tape and reel | 25 000 | | |
| BYT54M | BYT54M-TAP | 5000 per ammopack | 25 000 | | |

| PARTS TABLE | | | | | |
|-------------|--|---------|--|--|--|
| PART | TYPE DIFFERENTIATION | PACKAGE | | | |
| BYT54A | V _R = 50 V; I _{F(AV)} = 1.25 A | SOD-57 | | | |
| BYT54B | V _R = 100 V; I _{F(AV)} = 1.25 A | SOD-57 | | | |
| BYT54D | V _R = 200 V; I _{F(AV)} = 1.25 A | SOD-57 | | | |
| BYT54G | $V_R = 400 \text{ V}; I_{F(AV)} = 1.25 \text{ A}$ | SOD-57 | | | |
| BYT54J | $V_R = 600 \text{ V}; I_{F(AV)} = 1.25 \text{ A}$ | SOD-57 | | | |
| BYT54K | $V_R = 800 \text{ V}; I_{F(AV)} = 1.25 \text{ A}$ | SOD-57 | | | |
| BYT54M | V _R = 1000 V; I _{F(AV)} = 1.25 A | SOD-57 | | | |

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| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|--|--------|--------------------|-------------|------|--|--|
| PARAMETER | TEST CONDITION | PART | SYMBOL | VALUE | UNIT | | |
| | | BYT54A | $V_R = V_{RRM}$ | 50 | V | | |
| | | BYT54B | $V_R = V_{RRM}$ | 100 | V | | |
| | | BYT54D | $V_R = V_{RRM}$ | 200 | V | | |
| Reverse voltage = repetitive peak reverse voltage | See electrical characteristics | BYT54G | $V_R = V_{RRM}$ | 400 | V | | |
| 10voloo voltage | | BYT54J | $V_R = V_{RRM}$ | 600 | V | | |
| | | BYT54K | $V_R = V_{RRM}$ | 800 | V | | |
| | | BYT54M | $V_R = V_{RRM}$ | 1000 | V | | |
| Peak forward surge current | t _p = 10 ms, half sine wave | | I _{FSM} | 30 | Α | | |
| Average feminard animont | I = 10 mm | | I _{F(AV)} | 1.25 | Α | | |
| Average forward current | On PC board | | I _{F(AV)} | 0.75 | А | | |
| | | BYT54J | E _R | 10 | mJ | | |
| Non repetitive reverse avalanche energy | I _{(BR)R} = 0.4 A | BYT54K | E _R | 10 | mJ | | |
| | | BYT54M | E _R | 10 | mJ | | |
| Junction and storage temperature range | | | $T_j = T_{stg}$ | -55 to +175 | °C | | |

| MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|--|-----------------------------|-----|------|--|--|
| PARAMETER | TEST CONDITION | TEST CONDITION SYMBOL VALUE | | UNIT | | |
| Junction ambient | Lead length I = 10 mm, T _L = constant | R _{thJA} | 45 | K/W | | |
| | On PC board with spacing 25 mm | R _{thJA} | 100 | K/W | | |

| ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|--|------|-----------------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 1 A | | V_{F} | - | - | 1.5 | V |
| Reverse current | $V_R = V_{RRM}$ | | I _R | - | - | 5 | μΑ |
| | $V_R = V_{RRM}$, $T_j = 150$ °C | | I _R | - | - | 150 | μΑ |
| Reverse recovery time | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R = 0.25 \text{ A}$ | | t _{rr} | - | - | 100 | ns |

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

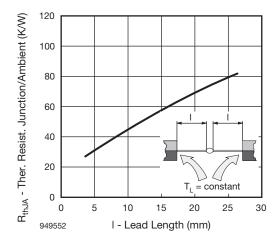


Fig. 1 - Max. Thermal Resistance vs. Lead Length

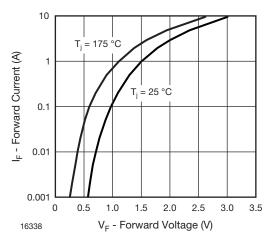


Fig. 2 - Forward Current vs. Forward Voltage

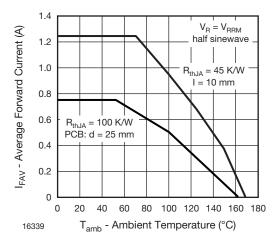


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

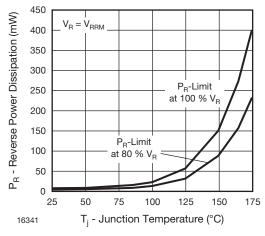


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

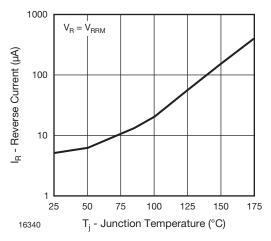


Fig. 4 - Max. Reverse Current vs. Junction Temperature

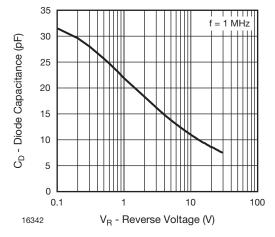
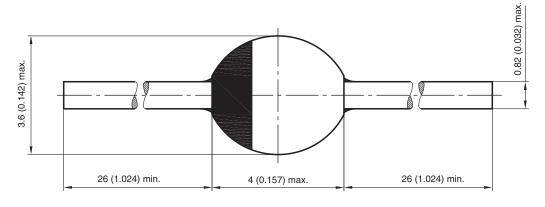


Fig. 6 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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